

Dual N-Channel PowerTrench[®] MOSFET 80 V, 66 A, 4.7 m Ω

Features

- Common Source Configuration to Eliminate PCB Routing
- Large Source Pad on Bottom of Package for Enhanced Thermals
- Max r_{DS(on)} = 4.7 mΩ at V_{GS} = 10 V, I_D = 16 A
- Max r_{DS(on)} = 6.4 mΩ at V_{GS} = 8 V, I_D = 14 A
- Ideal for Flexible Layout in Secondary Side Synchronous Rectification
- 100% UIL Tested
- Termination is Lead-free and RoHS Compliant

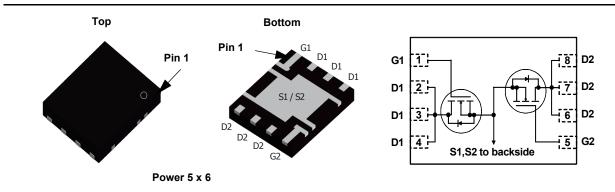
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General Description

This package integrates two N-Channel devices connected internally in common-source configuration. This enables very low package parasitics and optimized thermal path to the common source pad on the bottom. Provides a very small footprint (5 x 6 mm) for higher power density.

Applications

- Isolated DC-DC Synchronous Rectifiers
- Common Ground Load Switches



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted.

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			80	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous	T _C = 25 °C	(Note 5)	66		
	-Continuous	T _C = 100 °C	(Note 5)	42	Α	
ID	-Continuous	T _A = 25 °C	(Note 1a)	16		
	-Pulsed		(Note 4)	487		
E _{AS}	Single Pulse Avalanche Energy (Note 3)			337	mJ	
D	Power Dissipation	T _C = 25 °C		39	w	
PD	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	vv	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	
Thermal Cl	haracteristics					
$R_{\theta JC}$	Thermal Resistance, Junction to Case		3.2	°C/W		
R _{0JA}	Thermal Resistance, Junction to Ambient (Note 1a)			55	C/W	

Device Marking	Device	Package	Reel Size	Tape Width	Quantity	
FDMD8680	FDMD8680	Power 5 x 6	13 "	12 mm	3000 units	

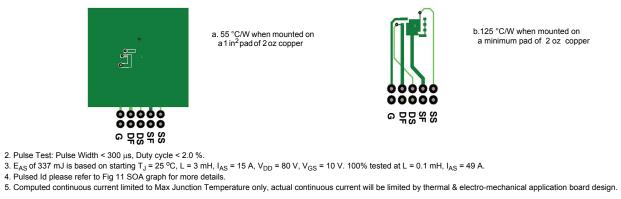
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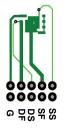
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units	
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	80			V	
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, referenced to 25 °C		50		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 64 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	2.0	3.0	4.0	V	
$\Delta V_{GS(th)}$ $\Delta T_{.1}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-10		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 16 A		3.3	4.7		
		V _{GS} = 8 V, I _D = 14 A		3.9	6.4	mΩ	
		V_{GS} = 10 V, I_{D} = 16 A, T_{J} = 125 °C		5.6	8.0	1	
9 _{FS}	Forward Transconductance	V _{DD} = 10 V, I _D = 16 A		49		S	
C _{iss}	Characteristics Input Capacitance Output Capacitance	V _{DS} = 40 V, V _{GS} = 0 V		3805	5330	pF	
C _{oss}	Output Capacitance	$v_{DS} = 40^{\circ} v_{, v_{GS}} = 0^{\circ} v_{, v_{GS}}$		657	920	pF	
C _{rss}	Reverse Transfer Capacitance			26	77	pF	
R _g	Gate Resistance		0.1	1.7	3.4	Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			20	32	ns	
t _r	Rise Time	V _{DD} = 40 V, I _D = 16 A		18	32	ns	
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		30	48	ns	
t _f	Fall Time			10	20	ns	
Q _{g(TOT)}	Total Gate Charge	V_{GS} = 0 V to 10 V V_{DD} = 40 V		53	73	nC	
Q _{gs}	Gate to Source Charge	$I_{\rm D} = 16 {\rm A}$		17		nC	
Q _{gd}	Gate to Drain "Miller" Charge			10		nC	
Drain-Sou	urce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 16 A$ (Note 2)		0.8	1.3	V	
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.7	1.2	V	
t _{rr}	Reverse Recovery Time	I _F = 16 A, di/dt = 100 A/μs		48	77	ns	
Yr .							

NOTES:

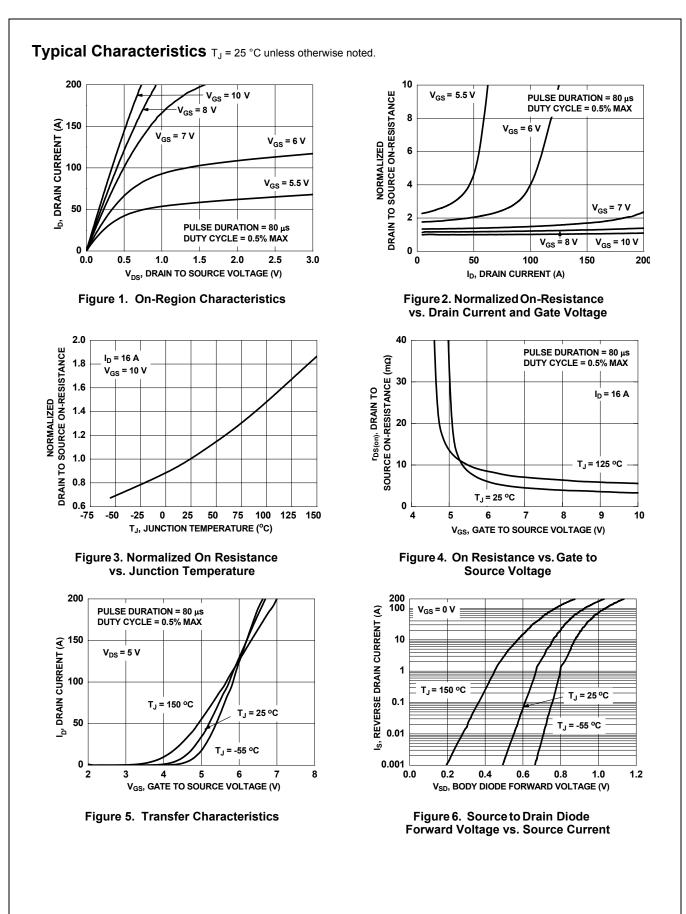
1. R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0CA} is determined by the user's board design.



a. 55 °C/W when mounted on a 1 in² pad of 2 oz copper

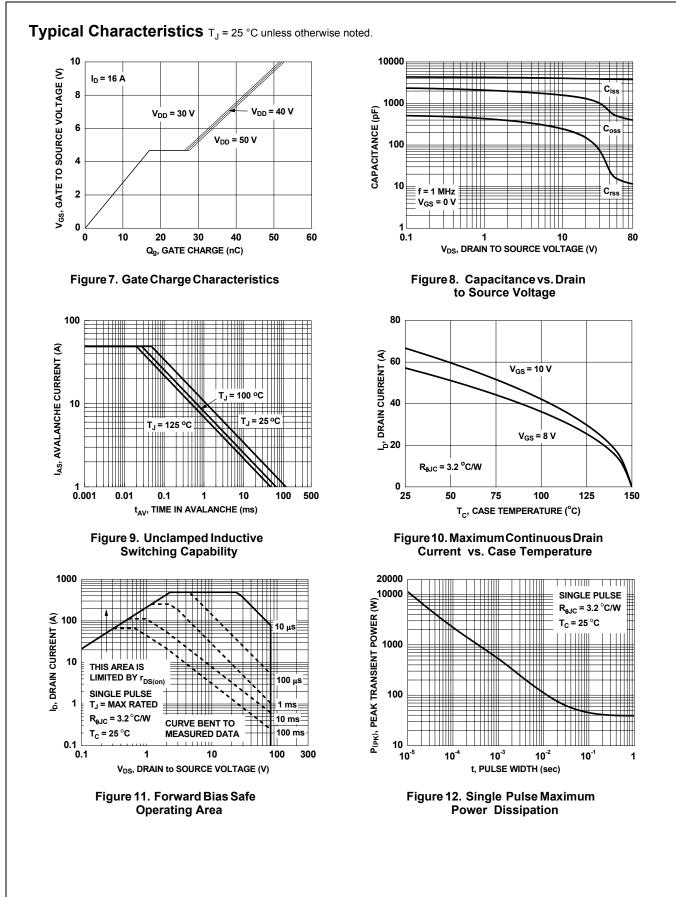


b.125 °C/W when mounted on a minimum pad of 2 oz copper

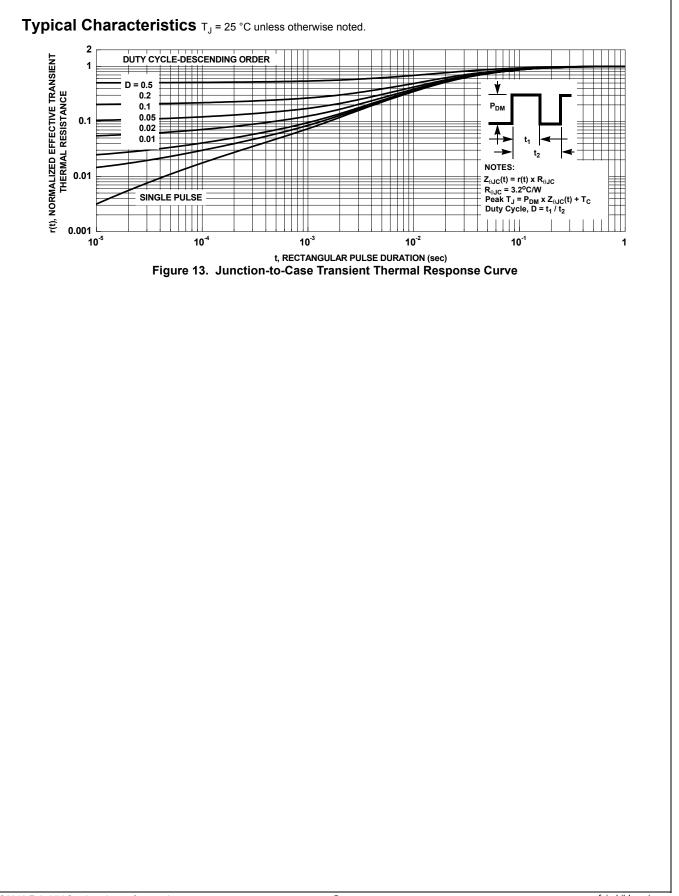


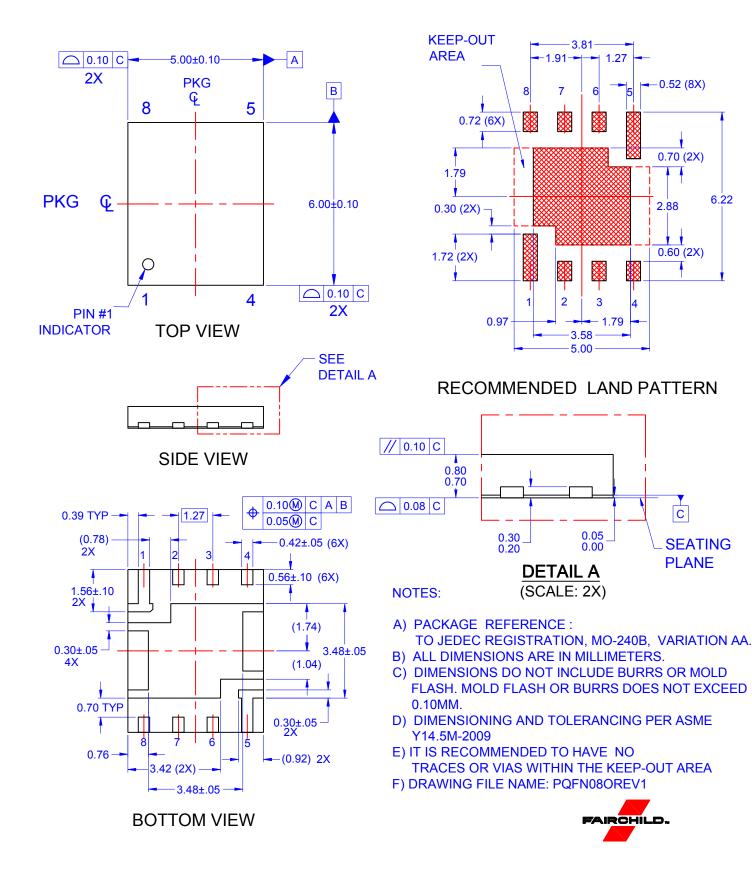
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